## PNP SILICON LOW POWER TRANSISTOR <br> Qualified per MIL-PRF-19500/350

## DEVICES

| 2N3867 | 2N3867S |
| :--- | :--- |
| 2N3868 | 2N3868S |

## LEVELS

JAN
JANTX JANTXV JANS

ABSOLUTE MAXIMUM RATINGS ( $T_{C}=+25^{\circ} \mathrm{C}$ unless otherwise noted)

| Parameters / Test Conditions | Symbol | 2N3867 | 2N3868 | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Collector-Base Voltage | $\mathrm{V}_{\text {CBO }}$ | 40 | 60 | Vdc |
| Collector-Emitter Voltage | $\mathrm{V}_{\text {CEO }}$ | 40 | 60 | Vdc |
| Emitter-Base Voltage | $\mathrm{V}_{\text {EBO }}$ | 4.0 | Vdc |  |
| Collector Current | $\mathrm{I}_{\mathrm{C}}$ | 3.0 | mAdc |  |
| Total Power Dissipation @ $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}^{(1)}$ | $\mathrm{P}_{\mathrm{T}}$ | 1.0 | $\mathrm{~W} /{ }^{\circ} \mathrm{C}$ |  |
| Operating \& Storage Junction Temperature Range | $\mathrm{T}_{\mathrm{J}}, \mathrm{T}_{\text {stg }}$ | -65 to +200 | ${ }^{\circ} \mathrm{C}$ |  |

## THERMAL CHARACTERISTICS

| Parameters / Test Conditions | Symbol | Max. | Unit |
| :---: | :---: | :---: | :---: |
| Thermal Resistance, Junction-to-Ambient | $\mathrm{R}_{\theta \mathrm{JA}}$ | 175 | ${ }^{\circ} \mathrm{C} / \mathrm{mW}$ |

Note: * Electrical characteristics for "S" suffix devices are identical to the "non S" corresponding devices.
1/ Derate linearly $5.71 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ for $\mathrm{T}_{\mathrm{A}}>+25^{\circ} \mathrm{C}$
2/ Derate linearly $57.1 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ for $\mathrm{T}_{\mathrm{C}}>+25^{\circ} \mathrm{C}$

## ELECTRICAL CHARACTERISTICS $\left(T_{A}=+25^{\circ} \mathrm{C}\right.$, unless otherwise noted)

| Parameters / Test Conditions |  | Symbol | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERTICS |  |  |  |  |  |
| Collector-Emitter Breakdown Cu $\mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{Adc}$ | $\begin{aligned} & \text { nt } \\ & \text { 2N3867, S } \\ & \text { 2N3868, S } \end{aligned}$ | $\mathrm{V}_{\text {(BR)CEO }}$ | $\begin{aligned} & 40 \\ & 60 \end{aligned}$ |  | Vdc |
| Collector-Base Cutoff Current $\begin{aligned} & \mathrm{V}_{\mathrm{CB}}=40 \mathrm{Vdc} \\ & \mathrm{~V}_{\mathrm{CB}}=60 \mathrm{Vdc} \\ & \hline \end{aligned}$ | $\begin{aligned} & \text { 2N3867, S } \\ & \text { 2N3868, S } \end{aligned}$ | $\mathrm{I}_{\text {CBO }}$ |  | 100 | $\mu \mathrm{Adc}$ |
| Emitter-Base Cutoff Current $\mathrm{V}_{\mathrm{EB}}=4.0 \mathrm{Vdc}$ |  | $\mathrm{I}_{\text {EBO }}$ |  | 100 | $\mu \mathrm{Adc}$ |
| Collector-Emitter Cutoff Current $\mathrm{V}_{\mathrm{CE}}=40 \mathrm{Vdc}$ <br> $\mathrm{V}_{\mathrm{CE}}=60 \mathrm{Vdc}$ <br> $\mathrm{V}_{\mathrm{CE}}=40 \mathrm{Vdc}, \mathrm{T}_{\mathrm{A}}=+150^{\circ} \mathrm{C}$ <br> $\mathrm{V}_{\mathrm{CE}}=60 \mathrm{Vdc}, \mathrm{T}_{\mathrm{A}}=+150^{\circ} \mathrm{C}$ | $\begin{aligned} & \text { 2N3867, S } \\ & \text { 2N3868, S } \\ & \text { 2N3867, } \\ & \text { 2N3868, } \end{aligned}$ | $\mathrm{I}_{\text {CEX }}$ |  | $\begin{aligned} & 1.0 \\ & 1.0 \\ & 50 \\ & 50 \\ & \hline \end{aligned}$ | $\mu \mathrm{Adc}$ |



TO-5 * 2N3867, 2N3868


TO-39 * (TP-205AD) 2N3867S, 2N3868S

ELECTRICAL CHARACTERISTICS ( $T_{A}=+25^{\circ} \mathrm{C}$, unless otherwise noted) (CONT.)

| Parameters / Test Conditions |  | Symbol | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ON CHARACTERTICS ${ }^{(2)}$ |  |  |  |  |  |
| Forward-Current Transfer Ratio $\mathrm{I}_{\mathrm{C}}=500 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}$ | $\begin{aligned} & \text { 2N3867, S } \\ & \text { 2N3868, S } \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 35 \end{aligned}$ |  |  |
| $\mathrm{I}_{\mathrm{C}}=1.5 \mathrm{Adc}, \mathrm{V}_{\mathrm{CE}}=2.0 \mathrm{Vdc}$ | $\begin{aligned} & \text { 2N3867, S } \\ & \text { 2N3868, S } \end{aligned}$ |  | $\begin{aligned} & 40 \\ & 30 \end{aligned}$ | $\begin{aligned} & 200 \\ & 150 \end{aligned}$ |  |
| $\mathrm{I}_{\mathrm{C}}=2.5 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=3.0 \mathrm{Vdc}$ | $\begin{aligned} & \text { 2N3867, S } \\ & \text { 2N3868, S } \end{aligned}$ | $\mathrm{h}_{\text {FE }}$ | $\begin{aligned} & 25 \\ & 20 \end{aligned}$ |  |  |
| $\mathrm{I}_{\mathrm{C}}=3.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}$ | $\begin{aligned} & \text { 2N3867, S } \\ & \text { 2N3868, S } \end{aligned}$ |  | $\begin{aligned} & 20 \\ & 20 \end{aligned}$ |  |  |
| $\mathrm{I}_{\mathrm{C}}=500 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}, \mathrm{T}_{\mathrm{A}}=-55^{\circ} \mathrm{C}$ | $\begin{aligned} & \text { 2N3867, S } \\ & \text { 2N3868, S } \end{aligned}$ |  | $\begin{aligned} & 25 \\ & 17 \end{aligned}$ |  |  |
| Collector-Emitter Saturation Voltage $\mathrm{I}_{\mathrm{C}}=500 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=50 \mathrm{mAdc}$ <br> $\mathrm{I}_{\mathrm{C}}=1.5 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=150 \mathrm{mAdc}$ $\mathrm{I}_{\mathrm{C}}=2.5 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=250 \mathrm{mAdc}$ |  | $\mathrm{V}_{\mathrm{CE}(\text { sat })}$ |  | $\begin{gathered} 0.5 \\ 0.75 \\ 1.5 \end{gathered}$ | Vdc |
| Base-Emitter Saturation Voltage $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=500 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=50 \mathrm{mAdc} \\ & \mathrm{I}_{\mathrm{C}}=1.5 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=150 \mathrm{mAdc} \\ & \mathrm{I}_{\mathrm{C}}=2.5 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=250 \mathrm{mAdc} \end{aligned}$ | $\begin{aligned} & \text { 2N3867, S } \\ & \text { 2N3868, S } \end{aligned}$ | $\mathrm{V}_{\mathrm{BE}(\mathrm{sat})}$ | $\begin{gathered} 0.9 \\ 0.85 \end{gathered}$ | $\begin{aligned} & 1.0 \\ & 1.4 \\ & 1.4 \\ & 2.0 \end{aligned}$ | Vdc |

## DYNAMIC CHARACTERISTICS

| Parameters / Test Conditions | Symbol | Min. | Max. | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Magnitude of Common Emitter Small-Signal Short Circuit <br> Forward Current Transfer Ratio <br> $\mathrm{I}_{\mathrm{C}}=100 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}, \mathrm{f}=20 \mathrm{MHz}$ |  |  |  |  |
| Output Capacitance <br> $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0,100 \mathrm{kHz} \leq \mathrm{f} \leq 1.0 \mathrm{MHz}$ | 3 | 12 | $\mathrm{k} \Omega$ |  |
| Iutput Capacitance <br> $\mathrm{V}_{\mathrm{EB}}=3.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0,100 \mathrm{kHz} \leq \mathrm{f} \leq 1.0 \mathrm{MHz}$ | $\mathrm{C}_{\mathrm{obo}}$ |  | 120 | pF |

(2) Pulse Test: Pulse Width $=300 \mu \mathrm{~s}$, Duty Cycle $\leq 2.0 \%$

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## SWITCHING CHARACTERISTICS



## SAFE OPERATING AREA

## DC Test

$\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}, 1$ cycle, $\mathrm{t}=1.0 \mathrm{~s}$

## Test 1

$\mathrm{V}_{\mathrm{CE}}=3.33 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=3.0 \mathrm{Adc}$

## Test 2

$\mathrm{V}_{\mathrm{CE}}=40 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=160 \mathrm{mAdc} \quad 2 \mathrm{~N} 3867$,
$\mathrm{V}_{\mathrm{CE}}=60 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=80 \mathrm{mAdc} \quad 2 \mathrm{~N} 3868, \mathrm{~S}$

## PACKAGE DIMENSIONS



| Symbol | Dimensions |  |  |  | Note |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Inches |  | Millimeters |  |  |
|  | Min | Max | Min | Max |  |
| CD | . 305 | . 335 | 7.75 | 8.51 | 5,6 |
| CH | . 240 | . 260 | 6.10 | 6.60 |  |
| HD | . 335 | . 370 | 8.51 | 9.40 | 4, 5 |
| LC | . 200 TP |  | 5.08 TP |  | 7 |
| LD | . 016 | . 019 | 0.41 | 0.48 | 8,9 |
| LL | See note 8, 14 |  |  |  |  |
| LU | . 016 | . 019 | 0.41 | 0.48 | 8,9 |
| $\mathrm{L}_{1}$ |  | . 050 |  | 1.27 | 8,9 |
| $\mathrm{L}_{2}$ | . 250 |  | 6.35 |  | 8,9 |
| P | . 100 |  | 2.54 |  | 7 |
| Q |  | . 030 |  | 0.76 | 5 |
| TL | . 029 | . 045 | 0.74 | 1.14 | 3,4 |
| TW | . 028 | . 034 | 0.71 | 0.86 | 3 |
| R |  | . 010 |  | 0.25 | 10 |
| $\alpha$ | $45^{\circ} \mathrm{TP}$ |  | $45^{\circ} \mathrm{TP}$ |  | 7 |
| 1, 2, 10, 12, 13, 14 |  |  |  |  |  |

## NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. Beyond $r$ (radius) maximum, TW shall be held for a minimum length of $.011(0.28 \mathrm{~mm})$.
4. Dimension TL measured from maximum HD.
5. Body contour optional within zone defined by $\mathrm{HD}, \mathrm{CD}$, and Q .
6. CD shall not vary more than .010 inch $(0.25 \mathrm{~mm})$ in zone $P$. This zone is controlled for automatic handling.
7. Leads at gauge plane $.054+.001-.000$ inch $(1.37+0.03-0.00 \mathrm{~mm})$ below seating plane shall be within .007 inch $(0.18$ mm ) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC. The device may be measured by direct methods or by gauging procedure.
8. Dimension LU applies between $L_{1}$ and $L_{2}$. Dimension $L D$ applies between $L_{2}$ and $L L$ minimum. Diameter is uncontrolled in and beyond LL minimum.
9. All three leads.
10. The collector shall be internally connected to the case.
11. Dimension $r$ (radius) applies to both inside corners of tab.
12. In accordance with ASME Y14.5M, diameters are equivalent to $\phi \mathrm{x}$ symbology.
13. Lead $1=$ emitter, lead $2=$ base, lead $3=$ collector.
14. For non-S-suffix devices (TO-5), dimension $L L=1.5$ inches ( 38.10 mm ) min. and 1.75 inches ( 44.45 mm ) max. For Ssuffix types (TO-39), dimension $L L=.5$ inch ( 12.70 mm ) min. and .750 inch ( 19.05 mm ) max.

FIGURE 1. Physical dimensions (similar to TO-5, TO-39)

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